## SQ9945BEY



Vishay Siliconix

## Automotive Dual N-Channel 60 V (D-S) 175 °C MOSFET

| PRODUCT SUMMARY                           |       |  |  |  |
|---|-------|--|--|--|
| V <sub>DS</sub> (V)                       | 60    |  |  |  |
| $R_{DS(on)} (\Omega)$ at $V_{GS} = 10 V$  | 0.064 |  |  |  |
| $R_{DS(on)} (\Omega)$ at $V_{GS} = 4.5 V$ | 0.082 |  |  |  |
| I <sub>D</sub> (A) per leg                | 6     |  |  |  |
| Configuration                             | Dual  |  |  |  |
| Package                                   | SO-8  |  |  |  |

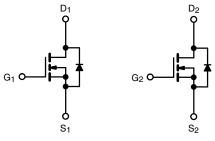


### FEATURES

- TrenchFET® power MOSFET
- 100 % R<sub>g</sub> and UIS tested
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



COMPLIANT HALOGEN



N-Channel MOSFET

N-Channel MOSFET

| <b>ABSOLUTE MAXIMUM RATINGS</b> ( $T_c = 25 \degree C$ , unless otherwise noted) |                         |                                   |             |      |
|--|-------------------------|-----------------------------------|-------------|------|
| PARAMETER  |                         | SYMBOL                            | LIMIT       | UNIT |
| Drain-Source Voltage   |                         | V <sub>DS</sub>                   | 60          | V    |
| Gate-Source Voltage  |                         | V <sub>GS</sub>                   | ± 20        |      |
| Continuous Drain Current   | T <sub>C</sub> = 25 °C  | Ι <sub>D</sub>                    | 5.4         |      |
|  | T <sub>C</sub> = 125 °C |                                   | 3.1         |      |
| Continuous Source Current (Diode Conduction) <sup>a</sup>                        |                         | I <sub>S</sub>                    | 3.6         | А    |
| Pulsed Drain Current <sup>b</sup>  |                         | I <sub>DM</sub>                   | 21.5        |      |
| Single Pulse Avalanche Current   | L = 0.1 mH              | I <sub>AS</sub>                   | 8.5         |      |
| Single Pulse Avalanche Energy  | L = 0.1 mm              | E <sub>AS</sub>                   | 3.6         | mJ   |
| Maximum Power Dissipation <sup>b</sup>   | T <sub>C</sub> = 25 °C  | P <sub>D</sub>                    | 4           | W    |
|  | T <sub>C</sub> = 125 °C |                                   | 1.3         |      |
| Operating Junction and Storage Temperature Range                                 |                         | T <sub>J</sub> , T <sub>stg</sub> | -55 to +175 | °C   |

| THERMAL RESISTANCE RATINGS |                        |                   |       |      |
|----------------------------|------------------------|-------------------|-------|------|
| PARAMETER                  |                        | SYMBOL            | LIMIT | UNIT |
| Junction-to-Ambient        | PCB Mount <sup>c</sup> | R <sub>thJA</sub> | 112   | °C/W |
| Junction-to-Foot (Drain)   |                        | R <sub>thJF</sub> | 38    | C/W  |

Notes

a. Package limited.

b. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.

c. When mounted on 1" square PCB (FR4 material).

nay Siliconix

**SQ9945BEY** 

MAX.

-

2.5 ± 100

> 1 50

150 -

0.064

0.110

0.137

0.082 -

> 470 88

36 12 1.5

2.6

6.66

9

4.2

26

3

21.5

1.1

\_

\_

-

\_

\_

\_

6

2.8

17

1.7

-

0.75

UNIT

V

nA

μΑ

А

Ω

S

pF

nC

Ω

ns

А

V

|                                  |   |   |   | Visha   |    |
|----------------------------------|---|---|---|---|----|
| unless otherw                    | vise noted)   |   |   |   |    |
| PARAMETER SYMBOL TEST CONDITIONS |   |   |   | TYP.  |    |
| •                                |   |   |   | •   |    |
| V <sub>DS</sub>                  | V <sub>GS</sub> =   | = 0 V, I <sub>D</sub> = 250 μA  | 60  | -   |    |
| V <sub>GS(th)</sub>              | V <sub>DS</sub> =   | = V <sub>GS</sub> , I <sub>D</sub> = 250 μΑ   | 1.5   | 2   |    |
| I <sub>GSS</sub>                 | V <sub>DS</sub> =   | -   | -   |   |    |
|                                  | $V_{GS} = 0 V$  | V <sub>DS</sub> = 60 V  | -   | -   |    |
| I <sub>DSS</sub>                 | $V_{GS} = 0 V$  | V <sub>DS</sub> = 60 V, T <sub>J</sub> = 125 °C   | -   | -   |    |
|                                  | $V_{GS} = 0 V$  | V <sub>DS</sub> = 60 V, T <sub>J</sub> = 175 °C   | -   | -   |    |
| I <sub>D(on)</sub>               | $V_{GS} = 10 V$   | $V_{DS} \ge 5 V$  | 20  | -   |    |
| R <sub>DS(on)</sub>              | V <sub>GS</sub> = 10 V  | I <sub>D</sub> = 3.4 A  | -   | 0.045   |    |
|                                  | $V_{GS} = 10 \text{ V}$   | $I_D = 3.4 \text{ A}, \text{ T}_J = 125 ^\circ\text{C}$   | -   | -   |    |
|                                  | $V_{GS} = 10 V$   | I <sub>D</sub> = 3.4 A, T <sub>J</sub> = 175 °C   | -   | -   |    |
|                                  | $V_{GS} = 4.5 V$  | I <sub>D</sub> = 3.7 A  | -   | 0.060   |    |
| <b>g</b> fs                      | $V_{DS} = 15 \text{ V}, \text{ I}_{D} = 3.7 \text{ A}$  |   | -   | 12  |    |
|                                  |   |   |   |   |    |
| C <sub>iss</sub>                 |   |   | -   | 375   |    |
| C <sub>oss</sub>                 | $V_{GS} = 0 V$  | $V_{GS} = 0 V$ $V_{DS} = 25 V$ , f = 1 MH   | $V_{DS} = 25 V$ , f = 1 MHz   | -   | 70 |
| C <sub>rss</sub>                 |   |   | -   | 30  |    |
| Qg                               |   |   | -   | 8   |    |
| Q <sub>gs</sub>                  | $V_{GS} = 10 V$   | $V_{DS} = 30 \text{ V}, \text{ I}_{D} = 4.3 \text{ A}$  | -   | 1.2   |    |
| Q <sub>gd</sub>                  |   |   | -   | 1.7   |    |
| R <sub>g</sub>                   |   | f = 1 MHz   | 1.1   | -   |    |
|                                  | SYMBOL   VDS   VGS(th)   IGSS   IDSS   ID(on)   RDS(on)   9fs   Ciss   Coss   Crss   Qg   Qgd | $\begin{tabular}{ c c c c c } \hline V_{DS} & V_{GS} & V_{DS} & V_{GS} & 0 & V_{GS} &$ | $\begin{tabular}{ c c c c } \hline SYMBOL & TEST CONDITIONS \\ \hline $V_{DS}$ & $V_{GS} = 0 \ V, \ I_D = 250 \ \mu A$ \\ \hline $V_{QS}(th)$ & $V_{DS} = V_{QS}, \ I_D = 250 \ \mu A$ \\ \hline $V_{QS}(th)$ & $V_{DS} = 0 \ V, \ V_{QS} = \pm 20 \ V$ \\ \hline $V_{QS} = 0 \ V$ & $V_{DS} = 60 \ V$ \\ \hline $V_{QS} = 0 \ V$ & $V_{DS} = 60 \ V, \ T_J = 125 \ ^{\circ}C$ \\ \hline $V_{QS} = 0 \ V$ & $V_{DS} = 60 \ V, \ T_J = 175 \ ^{\circ}C$ \\ \hline $V_{QS} = 0 \ V$ & $V_{DS} = 60 \ V, \ T_J = 175 \ ^{\circ}C$ \\ \hline $V_{QS} = 10 \ V$ & $V_{DS} = 50 \ V$ \\ \hline $V_{QS} = 10 \ V$ & $I_D = 3.4 \ A$ \\ \hline $V_{QS} = 10 \ V$ & $I_D = 3.4 \ A$, \ $T_J = 125 \ ^{\circ}C$ \\ \hline $V_{QS} = 10 \ V$ & $I_D = 3.4 \ A$, \ $T_J = 175 \ ^{\circ}C$ \\ \hline $V_{QS} = 10 \ V$ & $I_D = 3.4 \ A$, \ $T_J = 175 \ ^{\circ}C$ \\ \hline $V_{QS} = 10 \ V$ & $I_D = 3.4 \ A$, \ $T_J = 175 \ ^{\circ}C$ \\ \hline $V_{QS} = 4.5 \ V$ & $I_D = 3.7 \ A$ \\ \hline $V_{QS} = 4.5 \ V$ & $I_D = 3.7 \ A$ \\ \hline $V_{DS} = 15 \ V, \ I_D = 3.7 \ A$ \\ \hline $V_{DS} = 15 \ V, \ I_D = 3.7 \ A$ \\ \hline $V_{Qg} $ \\ \hline $V_{QS} = 0 \ V$ & $V_{DS} = 25 \ V, \ f = 1 \ MHz$ \\ \hline $C_{rss} $ \\ \hline $Q_{Qg} $ \\ \hline $Q_{Qg} $ \\ \hline $V_{QS} = 10 \ V$ & $V_{DS} = 30 \ V, \ I_D = 4.3 \ A$ \\ \hline $Q_{Qg} $ \\ \hline $V_{Qg} $ \\ \hline $V_{Qg} = 10 \ V$ & $V_{DS} = 30 \ V, \ I_D = 4.3 \ A$ \\ \hline $Q_{Qg} $ \\ \hline $V_{Qg} $ \\ \hline $V_{Qg} $ \\ \hline $V_{Qg} = 10 \ V$ \\ \hline $V_{DS} = 30 \ V, \ I_D = 4.3 \ A$ \\ \hline $V_{Qgd} $ \\ \hline $V_{DS} = 10 \ V$ \\ \hline $V_{DS} = 30 \ V, \ I_D = 4.3 \ A$ \\ \hline $V_{Qgd} $ \\ \hline $V_{DS} = 10 \ V$ \\ \hline $V_{DS} = 30 \ V, \ I_D = 4.3 \ A$ \\ \hline $V_{Qgd} $ \\ \hline $V_{DS} = 10 \ V$ \\ \hline $V_{DS} = 30 \ V, \ I_D = 4.3 \ A$ \\ \hline $V_{DS} = 4.5 \ V$ \\ \hline $V_{DS} = 4.5 \ V, \ I_D = 4.3 \ A$ \\ \hline $V_{DS} = 4.5 \ V$ \\ \hline $V_{DS} = 4$ | $\begin{tabular}{ c c c c c } \hline unless otherwise noted) \\ \hline $$YMBOL$ TEST CONDITIONS$ MIN. \\ \hline $$YMBOL$ V_{GS} = 0 V, I_D = 250 $\mu$A$ 60 \\ \hline $V_{GS(th)}$ V_{DS} = V_{GS}, I_D = 250 $\mu$A$ 1.5 \\ \hline $I_{GSS}$ V_{DS} = 0 V, V_{GS} = $\pm 20 V$ - \\ \hline $V_{GS} = 0 V$ V_{DS} = 60 V$ - \\ \hline $V_{GS} = 0 V$ V_{DS} = 60 V, T_J = 125 $^{\circ}C$ - \\ \hline $V_{GS} = 0 V$ V_{DS} = 60 V, T_J = 125 $^{\circ}C$ - \\ \hline $V_{GS} = 0 V$ V_{DS} = 60 V, T_J = 175 $^{\circ}C$ - \\ \hline $V_{GS} = 10 V$ V_{DS} = 60 V, T_J = 175 $^{\circ}C$ - \\ \hline $V_{GS} = 10 V$ I_D = 3.4 A$ - \\ \hline $V_{GS} = 10 V$ I_D = 3.4 A$, T_J = 125 $^{\circ}C$ - \\ \hline $V_{GS} = 10 V$ I_D = 3.4 A$, T_J = 175 $^{\circ}C$ - \\ \hline $V_{GS} = 10 V$ I_D = 3.4 A$, T_J = 175 $^{\circ}C$ - \\ \hline $V_{GS} = 10 V$ I_D = 3.4 A$, T_J = 175 $^{\circ}C$ - \\ \hline $V_{GS} = 4.5 V$ I_D = 3.7 A$ - \\ \hline $V_{GS} = 4.5 V$ I_D = 3.7 A$ - \\ \hline $V_{GS} = 0 V$ V_{DS} = 25 V, f = 1 MHz$ - \\ \hline $C_{rss}$ V_{GS} = 0 V$ V_{DS} = 30 V, I_D = 4.3 A$ - \\ \hline $Q_{gd}$ V_{GS} = 10 V$ V_{DS} = 30 V, I_D = 4.3 A$ - \\ \hline $V_{Ggd}$ V_{GS} = 10 V$ V_{DS} = 30 V, I_D = 4.3 A$ - \\ \hline $V_{Ggd}$ V_{GS} = 10 V$ V_{DS} = 30 V, I_D = 4.3 A$ - \\ \hline $V_{Ggd}$ V_{GS} = 10 V$ V_{DS} = 30 V, I_D = 4.3 A$ - \\ \hline $V_{DS} = 10 V$ V_{DS} = 10 V$ V_{DS} = 30 V, I_D = 4.3 A$ - \\ \hline $V_{Ggd}$ V_{GS} = 10 V$ V_{DS} = 30 V, I_D = 4.3 A$ - \\ \hline $V_{Ggd}$ V_{GS} = 10 V$ V_{DS} = 30 V, I_D = 4.3 A$ - \\ \hline $V_{Ggd}$ V_{GS} = 10 V$ V_{DS} = 30 V, I_D = 4.3 A$ - \\ \hline $V_{DS} = 10 V$ V_{DS} = 10 V$ V_{DS} = 10 V$ V_{DS} = 10 V$ - \\ \hline $V_{DS} = 10 V$ V_{DS} = 10 V$ V_{DS} = 4.3 A$ - \\ \hline $V_{DS} = 10 V$ V_{DS} = 4.3 A$ - \\ \hline $V_{DS} = 10 V$ V_{DS} = 10 V$ V_{DS} = 4.3 A$ - \\ \hline $V_{DS} = 10 V$ V_{DS} = 4.3 A$ - \\ \hline $V_{DS} = 10 V$ V_{DS} = 4.3 A$ - \\ \hline $V_{DS} = 10 V$ V_{DS} = 4.3 A$ - \\ \hline $V_{DS} = 10 V$ V_{DS} = 0 V$ V_{DS} = 0 V$ - \\ \hline $V_{DS} = 0 V$ V_{DS} = 0 V$ - \\ \hline $V_{DS} = 0 V$ - \\ \hline $V_$ |    |

t<sub>d(on)</sub>

t<sub>r</sub>

t<sub>d(off)</sub>

tf

I<sub>SM</sub>

V<sub>SD</sub>

#### Notes

Turn-On Delay Time c

Turn-Off Delay Time c

Rise Time <sup>c</sup>

Fall Time c

Pulsed Current<sup>a</sup>

Forward Voltage

a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.

Source-Drain Diode Ratings and Characteristics <sup>b</sup>

b. Guaranteed by design, not subject to production testing.

c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

 $V_{DD}$  = 30 V,  $R_L$  = 8.8  $\Omega$ 

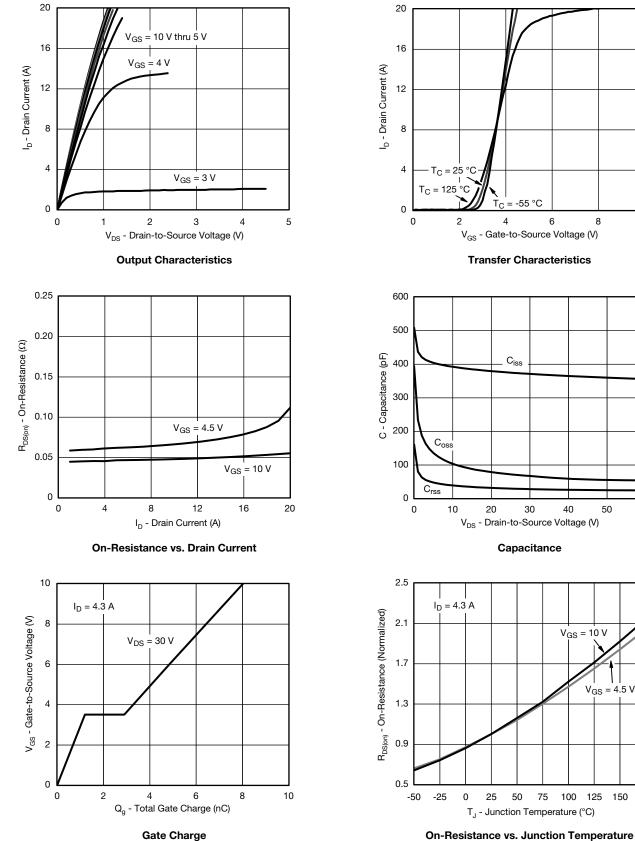
 $I_D \cong 3.4$  A,  $V_{GEN}$  = 10 V,  $R_g$  = 1  $\Omega$ 

 $I_{F} = 2 A, V_{GS} = 0 V$ 

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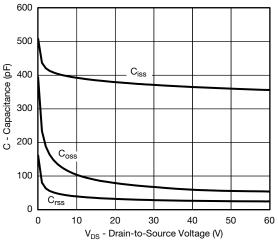
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## TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C, unless otherwise noted)

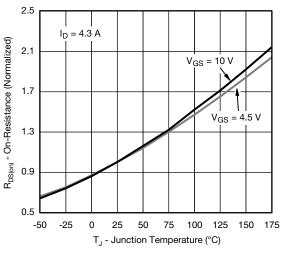


-55 °C 6 8 10  $V_{GS}$  - Gate-to-Source Voltage (V)

**Transfer Characteristics** 







S15-1873-Rev. D, 10-Aug-15

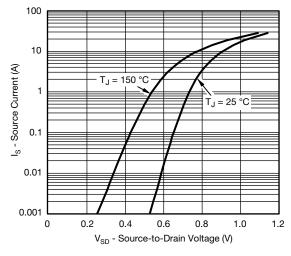
3

Document Number: 71504

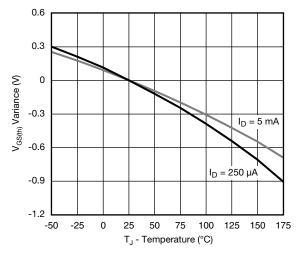
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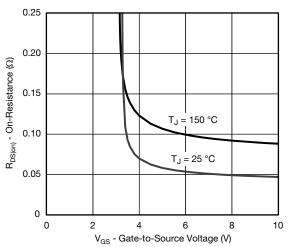
### TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C, unless otherwise noted)



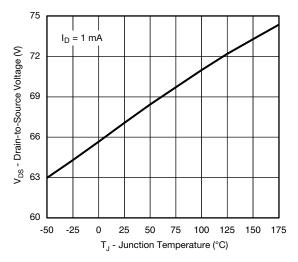
Source Drain Diode Forward Voltage



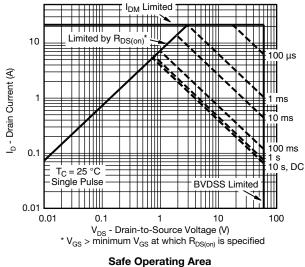
**Threshold Voltage** 



**On-Resistance vs. Gate-to-Source Voltage** 



Drain Source Breakdown vs. Junction Temperature



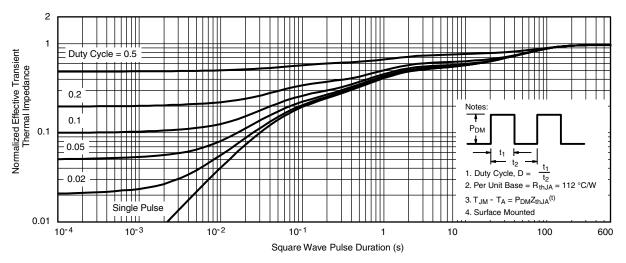
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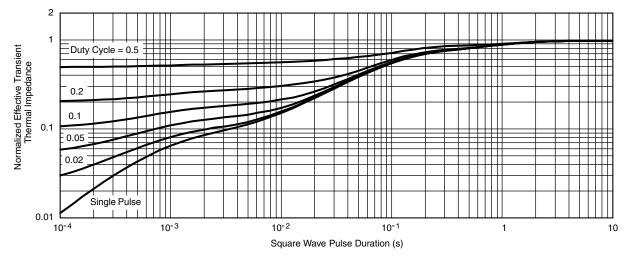


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### **THERMAL RATINGS** (T<sub>A</sub> = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient





#### Note

· The characteristics shown in the two graphs

- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)

- Normalized Transient Thermal Impedance Junction-to-Foot (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <a href="http://www.vishay.com/ppg?71504">www.vishay.com/ppg?71504</a>.



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| REVISION HISTORY <sup>a</sup> |           |                                      |  |
|-------------------------------|-----------|--------------------------------------|--|
| REVISION                      | DATE      | DESCRIPTION OF CHANGE                |  |
| D                             | 04-Aug-15 | Revised R <sub>g</sub> minimum limit |  |

Note

a. As of April 2014



# Package Information

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## SOIC (NARROW): 8-LEAD

JEDEC Part Number: MS-012





|   | MILLIM | IETERS | INCHES    |       |  |  |
|---|--------|--------|-----------|-------|--|--|
| DIM   | Min    | Мах    | Min       | Max   |  |  |
| A   | 1.35   | 1.75   | 0.053     | 0.069 |  |  |
| A <sub>1</sub>                              | 0.10   | 0.20   | 0.004     | 0.008 |  |  |
| В   | 0.35   | 0.51   | 0.014     | 0.020 |  |  |
| С   | 0.19   | 0.25   | 0.0075    | 0.010 |  |  |
| D   | 4.80   | 5.00   | 0.189     | 0.196 |  |  |
| E   | 3.80   | 4.00   | 0.150     | 0.157 |  |  |
| е   | 1.27   | BSC    | 0.050 BSC |       |  |  |
| н   | 5.80   | 6.20   | 0.228     | 0.244 |  |  |
| h   | 0.25   | 0.50   | 0.010     | 0.020 |  |  |
| L   | 0.50   | 0.93   | 0.020     | 0.037 |  |  |
| q   | 0°     | 8°     | 0°        | 8°    |  |  |
| S   | 0.44   | 0.64   | 0.018     | 0.026 |  |  |
| ECN: C-06527-Rev. I, 11-Sep-06<br>DWG: 5498 |        |        |           |       |  |  |

# **Application Note 826**

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**RECOMMENDED MINIMUM PADS FOR SO-8** 



Recommended Minimum Pads Dimensions in Inches/(mm)

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